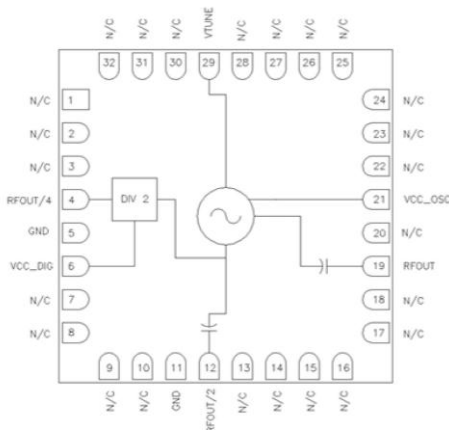


# RFVC1835

## 9.6GHz to 10.8GHz MMIC VCO with Fo/2 and Fo/4 Outputs

RFMD's RFVC1835 is a 5V InGaP MMIC VCO with an integrated frequency divider providing additional Fo/2 and Fo/4 outputs. With an Fo frequency range of 9.6GHz to 10.8GHz its monolithic structure provides excellent temperature, shock, and vibration performance. Output power (Fo) is +8dBm and is flat across the tuning voltage range of 1.5V to 14.5V. Phase noise is typically -114dBc/Hz at 100kHz offset. The device operates from a low supply current of 275mA which can be further reduced to 215mA by disabling the divider functions if not required. The RFVC1835 is available in a low cost 5mm x 5mm surface mount plastic overmolded QFN outline.



Functional Block Diagram

### Ordering Information

RFVC1835S2	Sample bag with 2 pieces
RFVC1835SB	Sample bag with 5 pieces
RFVC1835SQ	Bag with 25 pieces
RFVC1835SR	Bag with 100 pieces
RFVC1835TR7	7" Reel with 750 pieces
RFVC1835PCBA-410	Evaluation Board



Package: Plastic QFN, 32-pin, 5mm x 5mm x 0.85mm

### Features

- Multiple Frequency Outputs
  - Fo: 9.60GHz to 10.8GHz
  - Fo/2: 4.80GHz to 5.40GHz
  - Fo/4: 2.40GHz to 2.70GHz
- No External Resonator Required
- Integrated Frequency Divider
- Phase Noise: -114dBc/Hz at 100kHz Offset
- Flat Output Power Over Frequency Tuning Range 1.5V to 14.5V
  - Fo: 8dBm
  - Fo/2: 8dBm
  - Fo/4: -2dBm
- Low Power Consumption
  - 5V/275mA (Divider On)
  - 5V/215mA (Divider Off)
- 32-Lead 5mm x 5mm Plastic Overmolded QFN

### Applications

- Point-to-Point Radio
- Point-to-Multipoint Radio
- Satellite Communications
- Test Equipment
- Military
- Aerospace

## Absolute Maximum Ratings

Parameter	Rating	Unit
$V_{CC\_OSC}, V_{CC\_DIG}$	+5.5	V
$V_{TUNE}$	0 to +15	V
Junction Temperature ( $T_J$ )	135	°C
Continuous $P_{DISS}$ ( $T_A = 85^\circ\text{C}$ ) (derate 37mW/°C above $T_A = 85^\circ\text{C}$ )	1.65	W
Junction to Case, Thermal Resistance ( $R_{\theta(j-c)}$ )	30	°C/W
Storage Temperature	-65 to +150	°C
Operating Temperature	-40 to +85	°C
ESD Sensitivity (HBM)	Class 1A	



**Caution!** ESD sensitive device.



RFMD Green: RoHS compliant per EU Directive 2011/65/EU, halogen free per IEC 61249-2-21, <1000ppm each of antimony trioxide in polymeric materials and red phosphorus as a flame retardant, and <2% antimony solder.

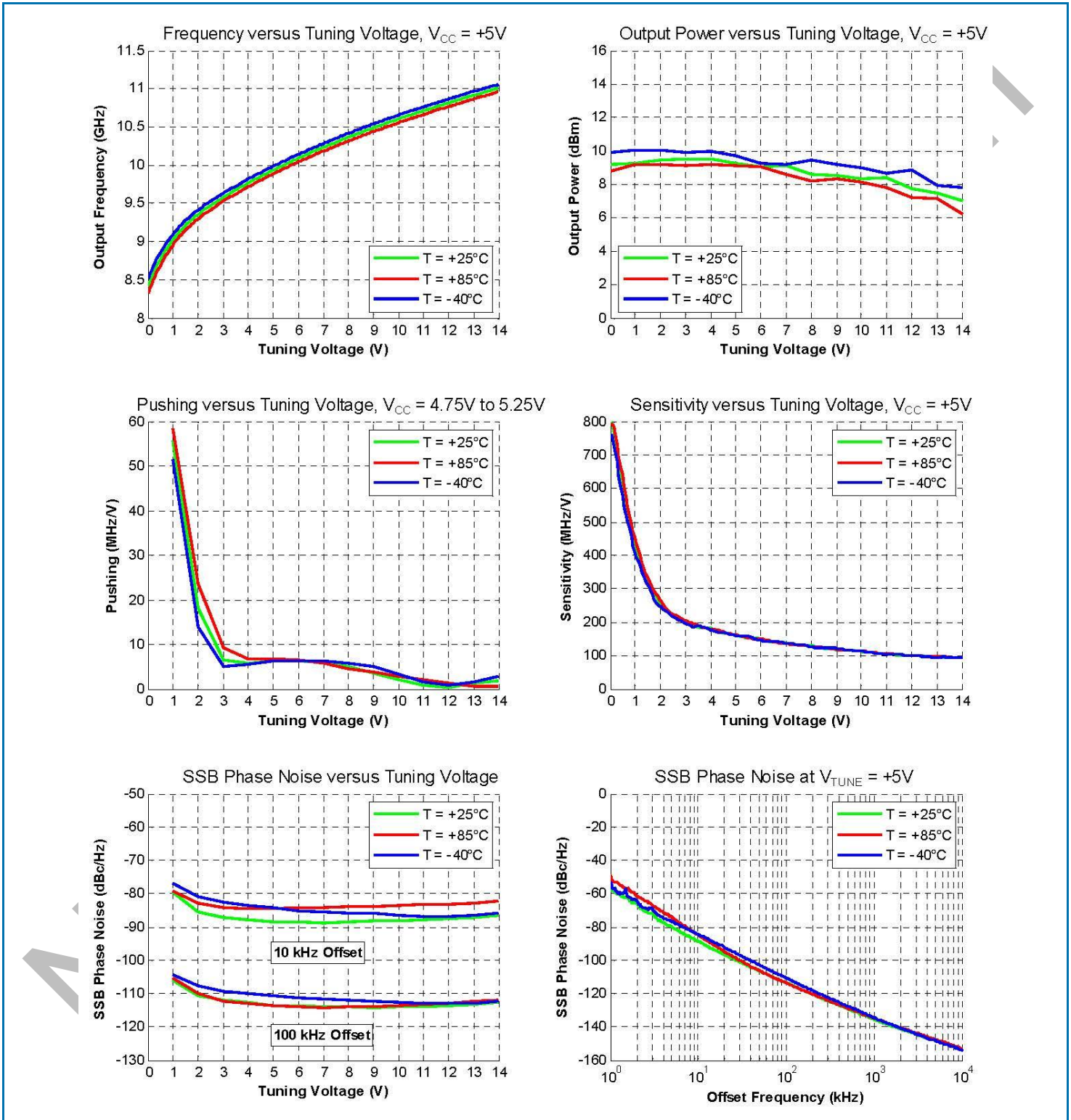
Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability. Specified typical performance or functional operation of the device under Absolute Maximum Rating conditions is not implied.

## Nominal Operating Parameters

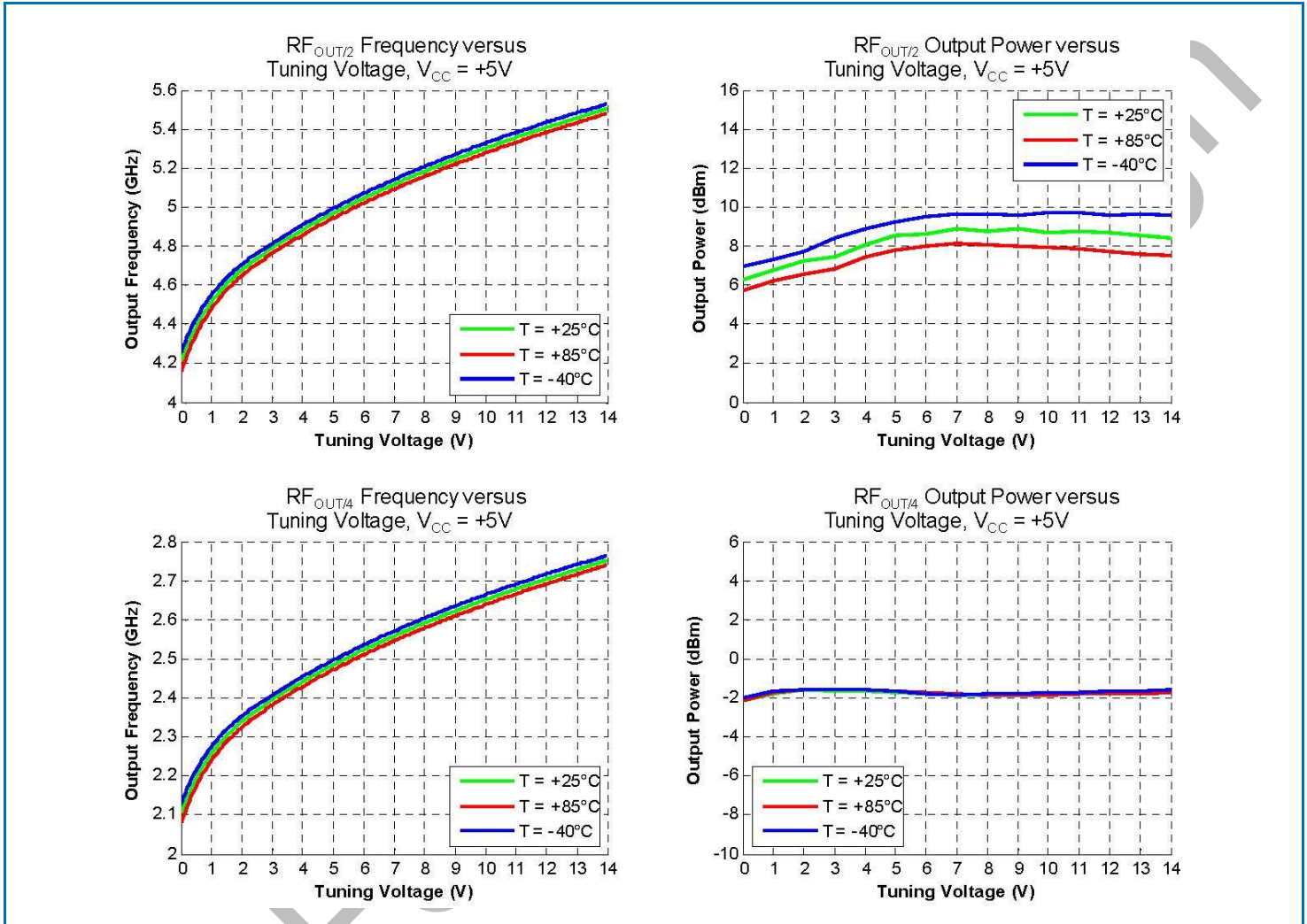
Parameter	Specification			Unit	Condition
	Min	Typ	Max		
<b>Electrical Specifications</b>					<b><math>V_{CC} = 5V, T_A = +25^\circ\text{C}</math></b>
Operating Frequency					
Fo	9.60		10.8	GHz	
Fo/2	4.80		5.40	GHz	
Fo/4	2.40		2.70	GHz	
Output Power					
Fo		8		dBm	
Fo/2		8		dBm	
Fo/4		-2		dBm	
SSB Phase Noise					
10 kHz offset at $RF_{OUT}$		-88		dBc/Hz	$V_{TUNE} = 5V$
100 kHz offset at $RF_{OUT}$		-114		dBc/Hz	
Tune Voltage	1.5		14.5	V	
Supply Current					
$V_{CC\_OSC}$		215		mA	
$V_{CC\_DIG}$		60		mA	
Tune Port Leakage Current		10		$\mu\text{A}$	
Output Return Loss		5		dB	

Parameter	Specification			Unit	Condition
	Min	Typ	Max		
<b>Electrical Specifications (continued)</b>					
Harmonics/Sub-harmonics					Measured with RF probes at package, not at SMA connections on EVB
1/2		35		dBc	
3/2		35		dBc	
2 <sup>nd</sup>		10		dBc	
3 <sup>rd</sup>		20		dBc	
Pulling (into a 2.0:1 VSWR)		5		MHz pp	
Pushing		25		MHz/V	
Frequency Drift Rate		0.8		MHz/°C	

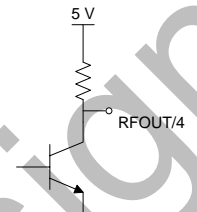

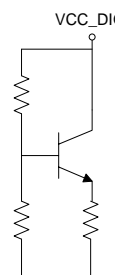
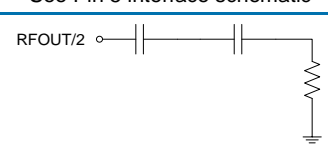
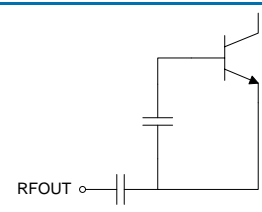
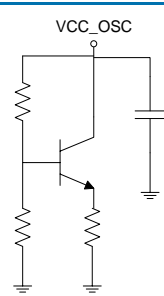
Typical Performance



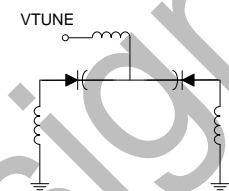
Typical Performance (continued)



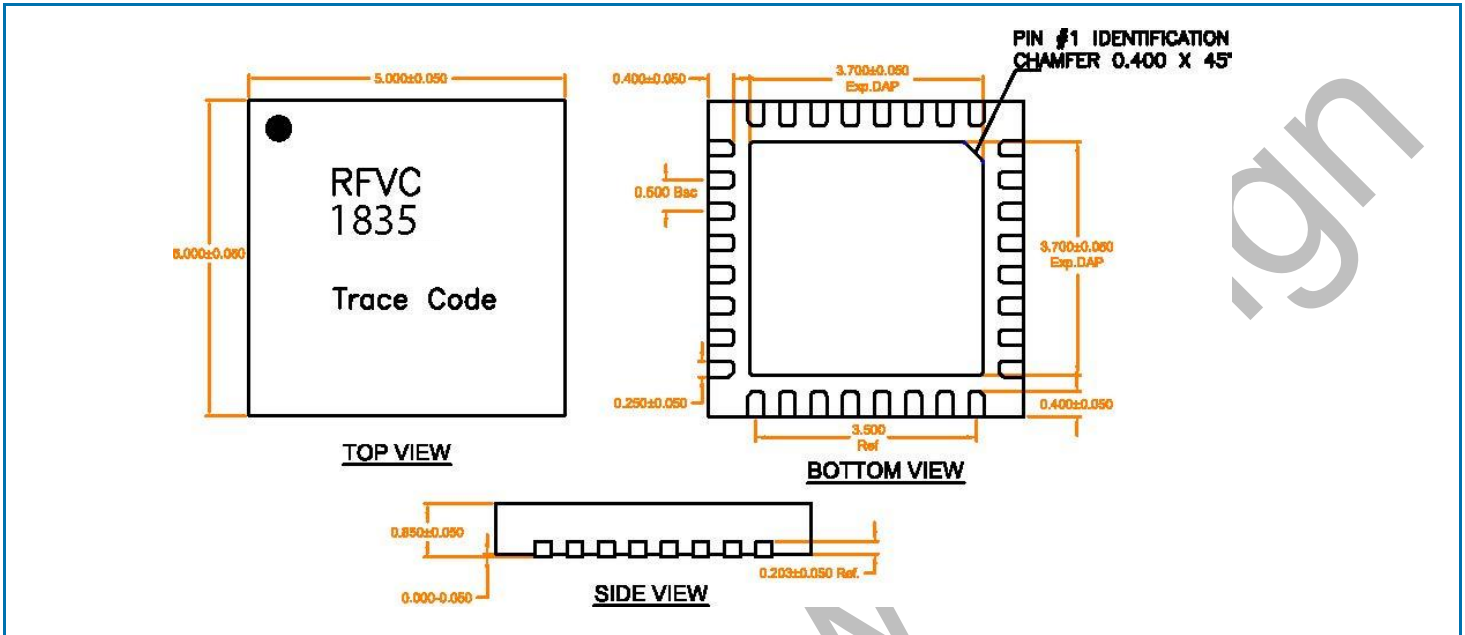
## Pin Names and Descriptions

Pin	Name	Description	Interface Schematic
1-3	N/C	No internal connection.	
4	RFOUT/4	VCO RF output at $F_o/4$ . Externally DC-blocked.	
5	GND	Connect to PCB ground.	
6	VCC_DIG	Supply voltage input for the integrated frequency divider. Typical +5V. Ground this pin to disable digital divider and reduce current consumption by 60mA.	
7-10	N/C	No internal connection.	
11	GND	Connect to PCB ground.	See Pin 5 interface schematic
12	RFOUT/2	VCO RF output at $F_o/2$ . Internally DC-blocked.	
13-18	N/C	No internal connection.	
19	RFOUT	VCO RF output at $F_o$ . Internally DC-blocked.	
20	N/C	No internal connection.	
21	VCC_OSC	Supply voltage input for the VCO. Typical +5V.	

### Pin Names and Descriptions (continued)

Pin	Name	Description	Interface Schematic
22-28	N/C	No internal connection.	
29	VTUNE	VCO control voltage input.	
30-32	N/C	No internal connection.	
PKG BASE	GND	Connect to PCB ground.	See Pin 5 interface schematic

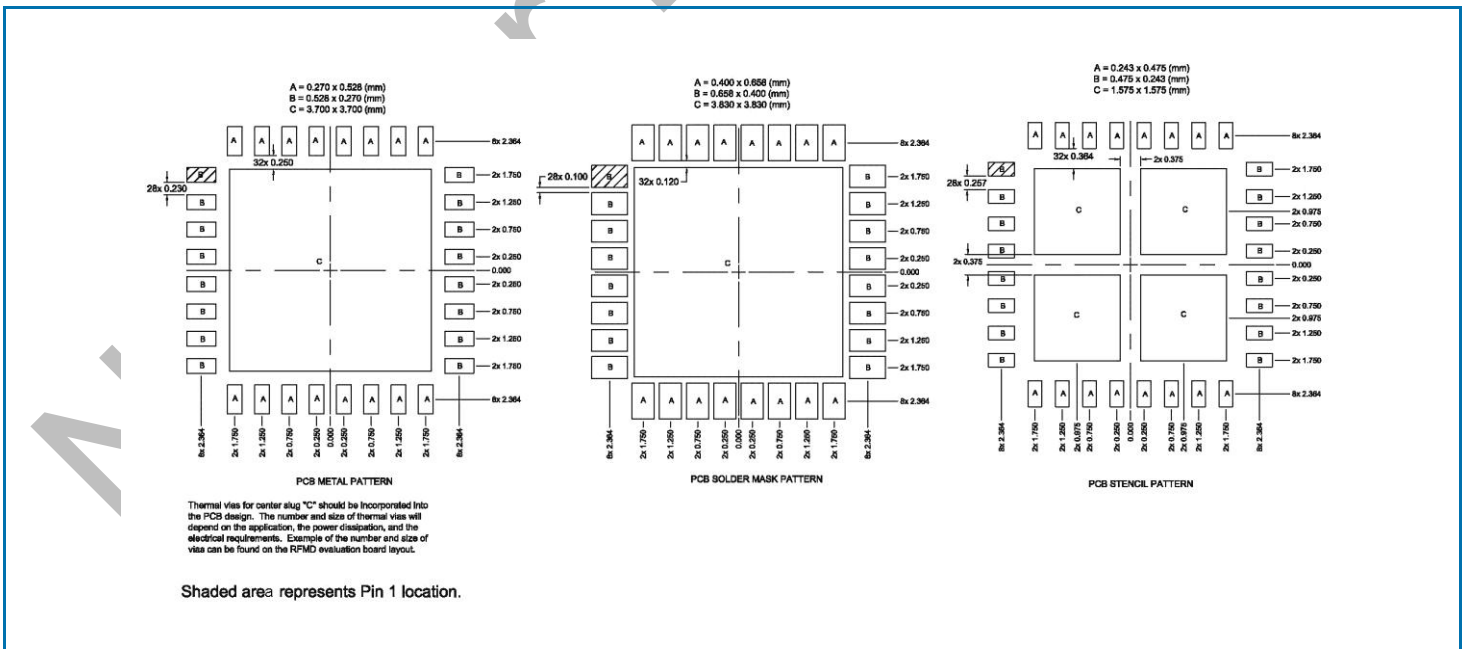
Package Drawing (all dimensions in mm)



Notes:

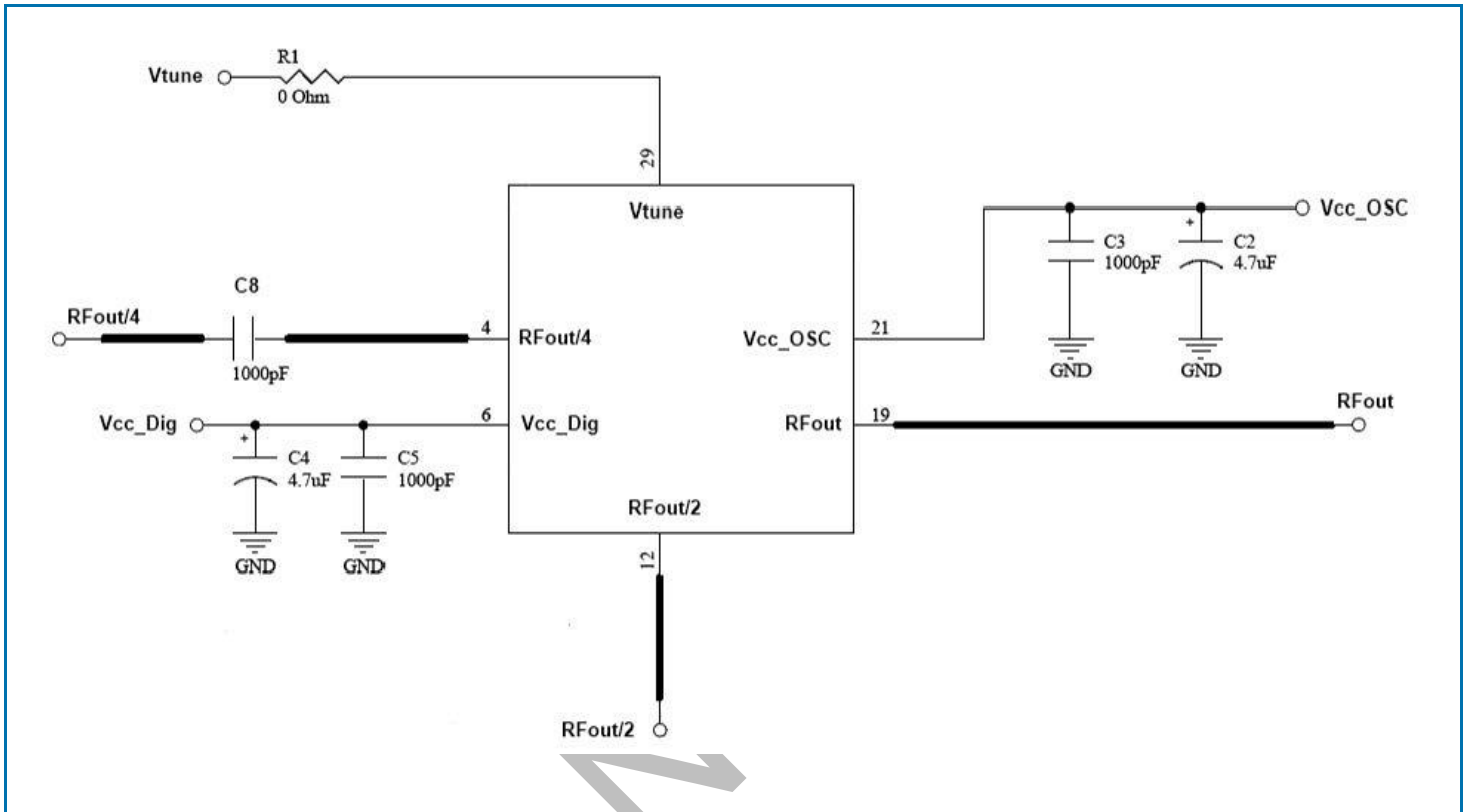
1. Dimensions are for reference only.
2. Package body material: Plastic.
3. Lead and paddle plating: 8µm minimum of Sn over Cu leadframe.

Recommended PCB Layout



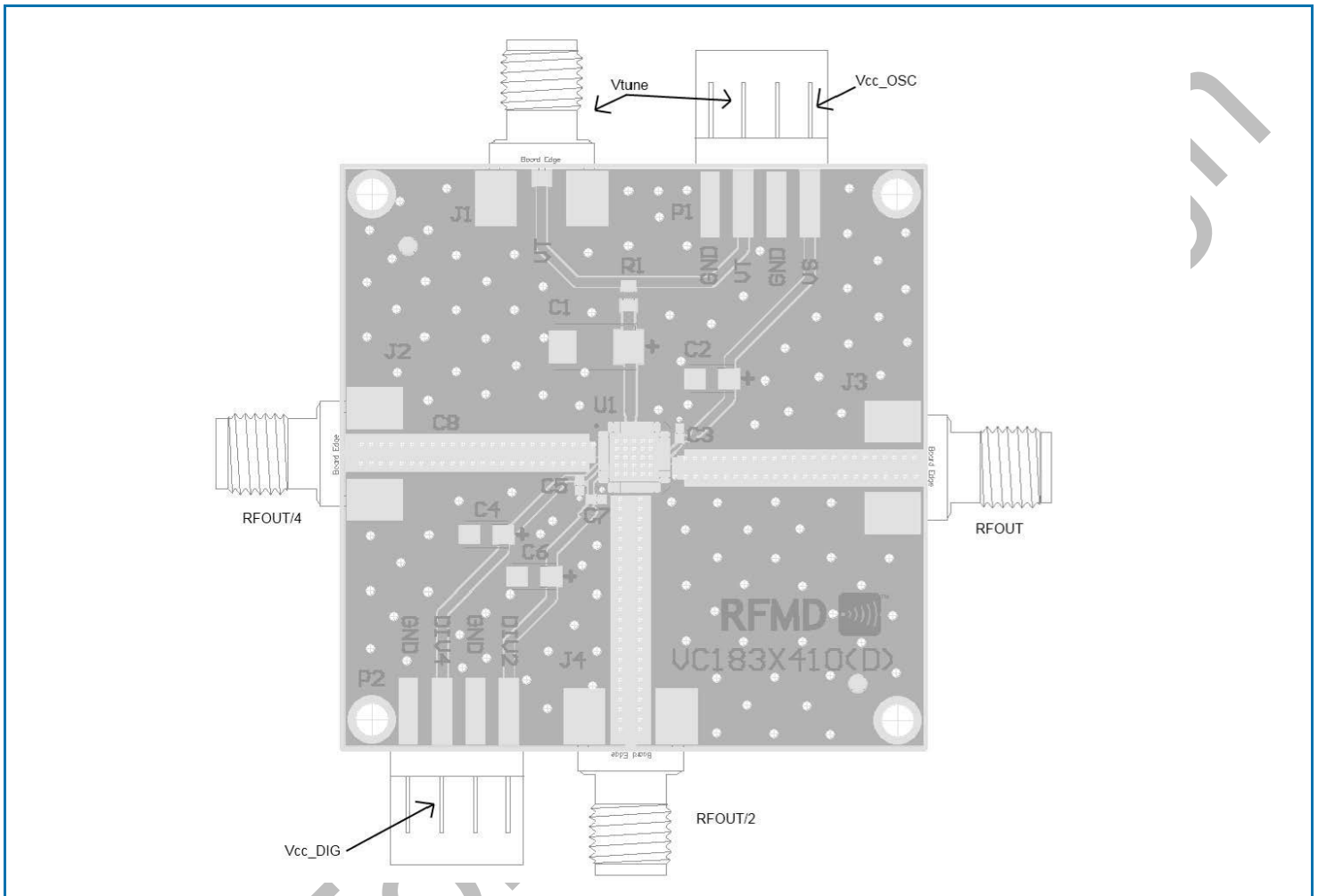


Sample Application Circuit Schematic



Bias Conditions	Output
$V_{CC\_OSC} = 5V$	$F_{OUT} = 10.0GHz$
$V_{CC\_DIG} = 5V$	$F_{OUT/2} = 5.00GHz$
$V_{TUNE} = 5V$	$F_{OUT/4} = 2.50GHz$

## Evaluation Board Layout



## Evaluation Board Bill of Materials (BOM)

Item	Description
U1	RFVC1835 VCO
C3, C5, C7, C8	1000pF Capacitor, 0402 Package
C2, C4, C6	4.7µF Tantalum Capacitor
C1	68µF Tantalum Capacitor
R1	0Ω Resistor, 0603 Package
P1, P2	4-PIN DC connector
J1, J2, J3, J4	PCB mount SMA connector
PCB	VC183x410(D)